| | | Monolithic Linear IC |
|-------|---------|--|
| N | 0.2310A | LA7311 |
| SANYO | | VTR-Use PAL/SECAM Discriminator S-VHS Discriminator |

The LA7311 is a PAL/SECAM discriminator and S-VHS discriminator IC. When used as PAL/SECAM discriminator, the LA7311 is highly resistant to noise and is capable of providing high sensitive discrimination, because it uses the FM demodulation, peak detection method. Further, the LA7311 uses very few external parts, making the space-saving and low-cost discrimination block available, because it requires neither ceramic filter nor resonance coil. When used as S-VHS discriminator, the LA7311 is also capable of providing high sensitive discrimination.

Features

Ordering number: EN 2310A

- Highly resistant to noise and burst input level variations and capable of providing high sensitive discrimination.
- Fewer external parts required (Neither ceramic filter nor resonance coil required)
- On-chip display LED drivers
- The polarity of burst gate pulse may be either positive or negative.

| Absolute Maximum Ratings at Ta | ι = 25°C | | unit |
|---|---------------------|-------------|------|
| Maximum Supply Voltage | V _{CC} max | 7.0 | V |
| Allowable Power Dissipation | P _d max | 130 | mW |
| Operating Temperature | Topr | -10 to +70 | °C |
| Storage Temperature | Tstg | -40 to +125 | °C |
| Operating Conditions at Ta = 25° | с | | unit |
| Recommended Supply Voltage | Vcc | 5.0 | v |
| Operating Voltage Range | Vccop | 4.5 to 6.0 | v |

| Operating Characteristics atTa=25°C, | V _{cc} =5V | | min | typ | max | unit |
|--|---------------------|---|-----|------|------|------|
| Current Dissipation | I _{CC} | | 6.7 | 9.6 | 12.4 | mΑ |
| F-V Conversion Gain (PB) | ΔVp | Difference between output at 4.4MHz and output at 4.25MHz | 75 | 105 | 135 | mV |
| F-V Conversion Gain (REC) | ΔV_R | Difference between output at 4.4MHz and output at 4.25MHz | 75 | 105 | 135 | mV |
| PAL \rightarrow SECAM Inversion Voltage Difference | V ₈₋₁₂ | | 35 | 50 | 65 | mV |
| R/P Switching Threshold Voltage | V _{3TH} | | 2.0 | 2.35 | 2.7 | v |
| BG Threshold Voltage I | V _{7TH} | | 1.5 | 1.7 | 1.9 | v |
| BG Threshold Voltage II | V _{11TH} | | 3.2 | 3.4 | 3.6 | v |
| Forced PAL Threshold Voltage | V _{10TH} | | 1.3 | 1.7 | 2.2 | v |
| Forced SECAM Threshold Voltage | V _{2TH} | | 1.7 | 2.0 | 2.3 | v |
| Discrimination Output Voltage I | V13 | I _D =5mA | 4.0 | 4.2 | 4.4 | v |
| Discrimination Output Voltage II | V15 | I _D =5mA | 4.0 | 4.2 | 4.4 | v |

Continued on next page.



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| Continued from preceding page. | | | | | | |
|--|-----------------|-------------------------|-----|-----|-----|-------|
| | | | min | typ | max | unit |
| Discrimination Output Leakage Current I | I13 (leak) | | | 0 | 5 | μA |
| Discrimination Output Leakage Current II | I15 (leak) | | | 0 | 5 | μA |
| Pin 12 DC Voltage | V ₁₂ | 4.43MHz, 100mVp-p input | 2.1 | 2.6 | 3.1 | Ū V |
| Input Burst Level | VIN | | 60 | 100 | 200 | mVp-p |
| Driver Saturation Voltage I | V14 | ID=20mA | | 170 | 400 | mV |
| Driver Saturation Voltage II | V ₁₆ | ID=20mA | | 170 | 400 | mV |

Test Circuit



Note: Remove the 1M Ω resistor connected across pins (1) and (9) and across pins (5) and (9) except when measuring ΔV_P , ΔV_R , V_{12} , V_{1N} .

| | S1 | S2 | S3 | S4 | S5 | S6 | Conditions | |
|-----------------------|-----|----------|----------|----------|-----|-----|--|--|
| I _{CC} | off | off | off | off | off | off | V9=5V | |
| ΔV _P | B | ↓ | Ļ | Ļ | Ļ | ļ | 100mV _{P.p.} difference between V ₈ (or V ₁₂) potential at 4.4MHz input and V ₈ (or V ₁₂) potential at 4.25MHz input | |
| ΔV_R | A | on | Ļ | Ļ | Ļ | 1 | $100mV_{p.p.}$ difference between V ₈ (or V ₁₂) potential at 4.4MHz input and V ₈ (or V ₁₂) potential at 4.25MHz input | |
| V ₈₋₁₂ | off | off | Ļ | А | ţ | ļ | a (rise from 0) when $V_7 = 0V$, $V_{11}=5V$, $V_8=1.9V$, $V_{12}=1.9V+a$, $V_{14}>4V$ | |
| V _{3TH} | Ļ | Ļ | Ļ | off | Ļ | ţ | V_3 (rise from 0) when $V_1 = V_7 = V_{11} = 0V$, $V_8 < 0.1V$ | |
| V _{7TH} | Ļ | , ↑ | ↓ | ↓ | ţ | Ļ | V ₇ (rise from 0) when V ₁₁ =5V, V8>1.0V | |
| V _{11TH} | Ļ | 1 1 | ↓ ↓ | ↓ | ţ | Ļ | V ₁₁ (fall from 5V) when V ₇ =0V, V8>1.0V | |
| V _{10TH} | Ļ | Ļ | ↓ | ļ | ţ | A | V_{10} (rise from 0) when $V_7 = V_{11} = 0V_1 V_1 =$ | |
| V _{2TH} | Ļ | Ļ | ↓ | A | Ļ | off | V ₂ (rise from 0) when V ₈ =V ₁₂ =3V, V14>4V | |
| V ₁₃ | Ļ | Ļ | Α | off | Ļ | Ļ | Pin 13 potential when $V_2=0V$, drive current 5mA | |
| V ₁₅ | Ļ | + | off | Ļ | A | ↓ | Pin 15 potential when V2=3V, drive current 5mA | |
| I _{13(leak)} | Ļ | Ļ | B | Ţ | off | ļ | $V_2=3V$, current which flows when pin 13 is connected to GND | |
| I _{15(leak)} | Ļ | ↓ · | off | Ļ | В | Ļ | $V_2=0V$, current which flows when pin 15 is connected to GND | |
| V _{14(sat)} | ↓ ↓ | ↓ | Ļ | В | off | ţ | Pin 14 potential when V ₂ =0V, drive current 20mA | |
| V _{16(sat)} | Ļ | ↓ | Ļ | off | Ļ | B | Pin 6 potential when $V_2=3V_1$ drive current 20mA | |
| V ₁₂ | A | on | Ļ | Ļ | ţ | off | 100mVp-p, 4.43MHz CW input, Apply 4µs BGP input to pin 11. | |
| VIN | A/B | on/off | Ļ | Ļ | Ļ | Ļ | | |

Equivalent Circuit Block Diagram and Sample Application Circuit (PAL/SECAM Discrimination)



Note 1: When the BGP is positive, apply an input to pin 7 and connect pin 11 to V_{CC} . Note 2: When pin 10 is not in use, bring pin 10 to the open state or connect to GND.



Sample S-VHS Discriminator

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Adjustment method: Adjust the VR (from VR center position) connected to pin 4 so that the DC voltage on pin 8 becomes 2.0V when the FM-Y signal at the (normal) VHS REC tape PB mode is input.

Note 1: When the BGP is negative, apply an input to pin 11 and connect pin 7 to GND. Note 2: Pin 5 may be connected to GND.

| Mode | Type of Cassette | Panel SW | V ₁₀ | V ₂ | Display |
|------|---------------------|----------|-----------------|--------------------------|---------|
| REC | N | S | Н | L | S |
| | N | N | L | н | N |
| | S | S | Н | L | S |
| | | N | L | н | N, |
| РВ | D.T. | S | L | Н | N |
| | IN | N | L | Н | N |
| | 6 | S | L | Automatic discrimination | |
| | | N | L | Automatic discrimination | |

N; NORMAL VHS, S; S-VHS

Input/Output Configuration

Unit (resistance : Ω) DC Voltage Pin Pin Name I/O Impedance or I/O Configuration Remarks 1 REC CHROMA IN 10kΩ 4.1V 2 SECAM HOLDER SECAM at 2.0V or greater REC at 2.4V ov 3) R/P CONTROL 3 (PB mode) or greater 20k 4 CURRENT SOURCE Open emitter 410mV PB CHROMA IN 10kΩ 4.1V 5 GND 0V 6 Burst gate at 1.7V or greater BGP IN ⊙-‱-K 7 Base PEAK FILTER 1 Emitter follower 8 9 Vcc 5V Forced PAL at 1.7V PAL HIGH IN ٥v 10 or greater Burst gate at 3.4V BGP IN 11 Base ሙ or less PEAK FILTER 2 Emitter follower 12 4.1V 13 PAL HIGH OUT Up to 5mA (PAL mode) (B) PAL DRIVE Up to 25mA 14 NPN open collector 4.1V 15 SECAM HIGH OUT Up to 5mA (SECAM mode) بلر ۱۹ 16 SECAM DRIVE NPN open collector Up to 25mA

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